



# PJQ4463AP-AU

## 60V P-Channel Enhancement Mode MOSFET

**Voltage**

**-60 V**

**Current**

**-4.2 A**

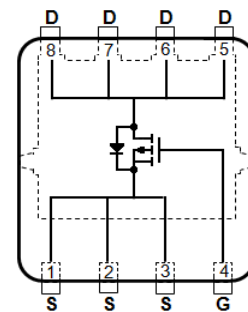
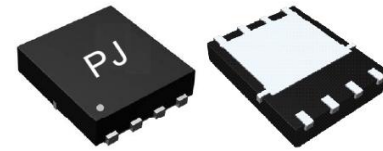
### Features

- $R_{DS(ON)}$ ,  $V_{GS}@-10V$ ,  $I_D@-6A < 68m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@-4.5V$ ,  $I_D@-3A < 85m\Omega$
- Advanced Trench Process Technology
- High density cell design for ultra low on-resistance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### Mechanical Data

- Case : DFN3333-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.001 ounces, 0.03 grams

DFN3333-8L



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		$V_{DS}$	-60	V
Gate-Source Voltage		$V_{GS}$	$\pm 20$	
Continuous Drain Current (Note 4)	$T_A=25^\circ\text{C}$	$I_D$	-4.2	A
	$T_A=70^\circ\text{C}$		-3.4	
Pulsed Drain Current (Note 1)		$I_{DM}$	-16.8	
Power Dissipation	$T_A=25^\circ\text{C}$	$P_D$	2.1	W
	$T_A=70^\circ\text{C}$		1.3	
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	$^\circ\text{C}$
Typical Thermal Resistance Junction to Ambient (Note 4,5)		$R_{\theta JA}$	59.5	$^\circ\text{C/W}$

- Limited only By Maximum Junction Temperature



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## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-1	-1.53	-2.5	
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-6A$	-	55	68	m $\Omega$
		$V_{GS}=-4.5V, I_D=-3A$	-	71	85	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=-60V, V_{GS}=0V$	-	-	-1	$\mu A$
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	$\pm 100$	nA
<b>Dynamic</b> (Note 6)						
Total Gate Charge	$Q_g$	$V_{DS}=-30V, I_D=-6A,$ $V_{GS}=-10V$ (Note 3)	-	17	-	nC
Gate-Source Charge	$Q_{gs}$		-	2.8	-	
Gate-Drain Charge	$Q_{gd}$		-	3.6	-	
Input Capacitance	$C_{iss}$	$V_{DS}=-30V, V_{GS}=0V,$ $f=1MHz$	-	879	-	pF
Output Capacitance	$C_{oss}$		-	70	-	
Reverse Transfer Capacitance	$C_{rss}$		-	47	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=-30V, I_D=-1A,$ $V_{GS}=-10V, R_G=6\Omega$ (Note 3)	-	8.4	-	ns
Turn-On Rise Time	$t_r$		-	30	-	
Turn-Off Delay Time	$t_{d(off)}$		-	52	-	
Turn-Off Fall Time	$t_f$		-	16	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$	---	-	-	-4.2	A
Diode Forward Voltage	$V_{SD}$	$I_S=-1A, V_{GS}=0V$	-	-0.73	-1	V

**NOTES :**

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics
3. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}=150^\circ\text{C}$ . Ratings are based on low frequency and duty cycles to keep initial  $T_J=25^\circ\text{C}$ .
4. The maximum current rating is package limited
5.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper
6. Guaranteed by design, not subject to production testing.



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## TYPICAL CHARACTERISTIC CURVES

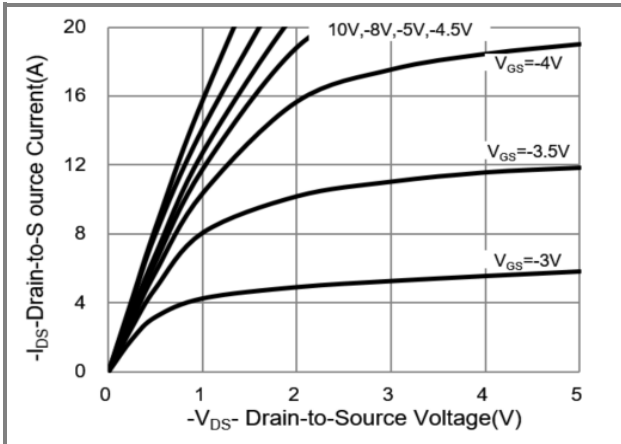


Fig.1 On-Region Characteristics

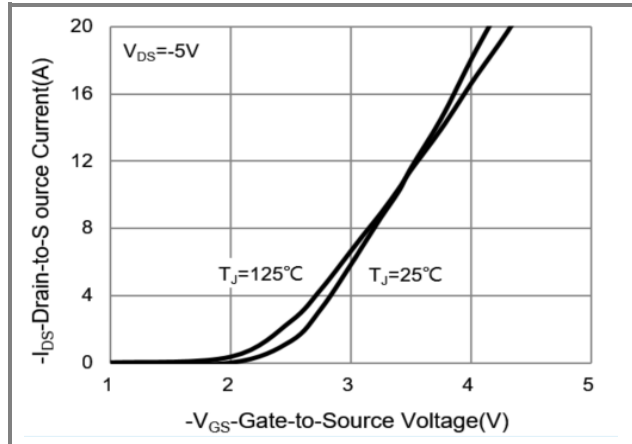


Fig.2 Transfer Characteristics

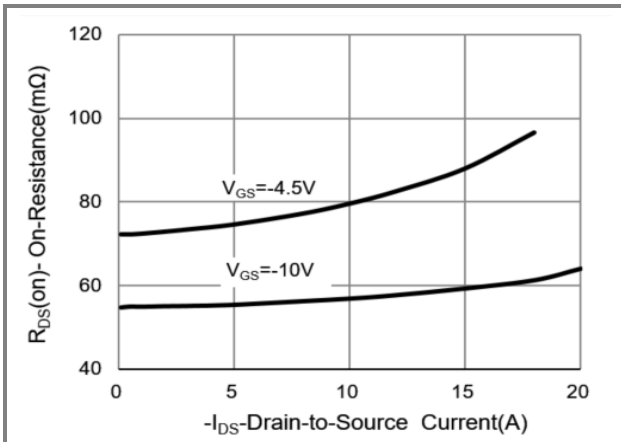


Fig.3 On-Resistance vs. Drain Current

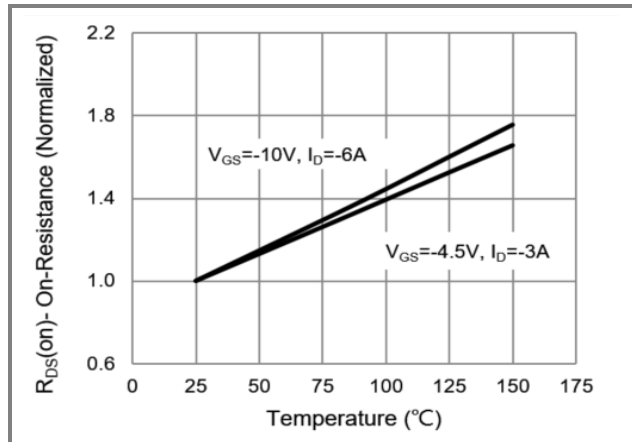


Fig.4 On-Resistance vs. Junction temperature

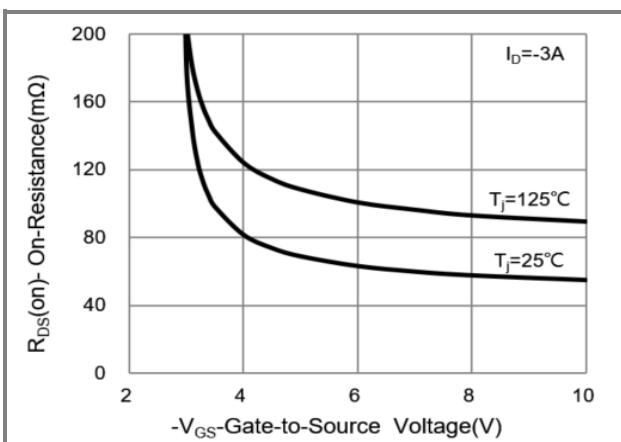


Fig.5 On-Resistance Variation with  $V_{GS}$

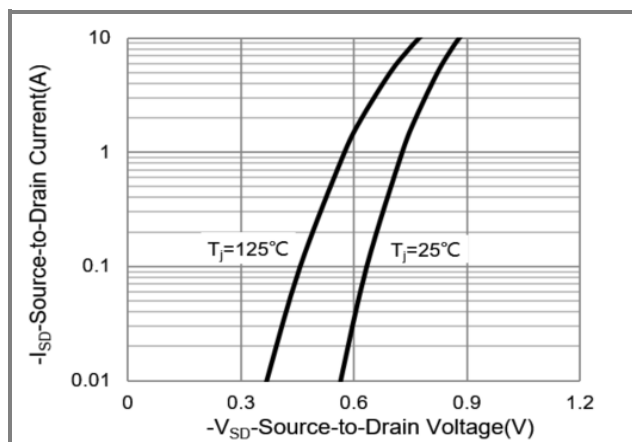


Fig.6 Source-Drain Diode Forward Voltage



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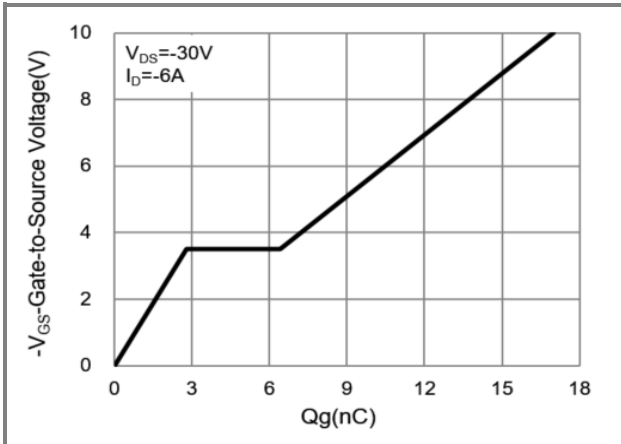


Fig.7 Gate-Charge Characteristics

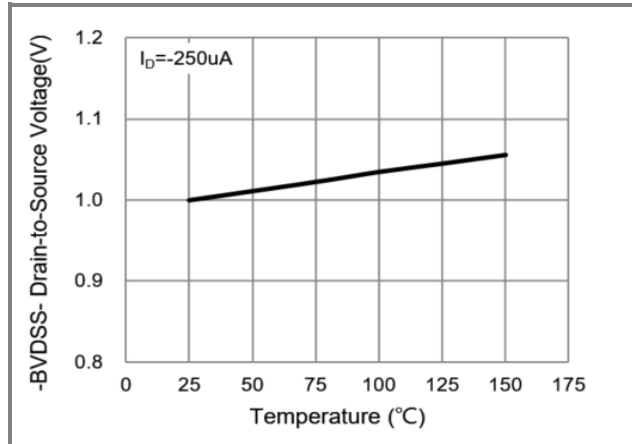


Fig.8 Breakdown Voltage Variation vs. Temperature

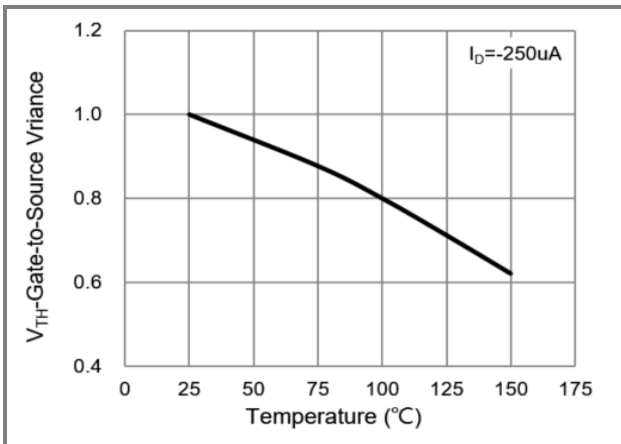


Fig.9 Threshold Voltage Variation with Temperature

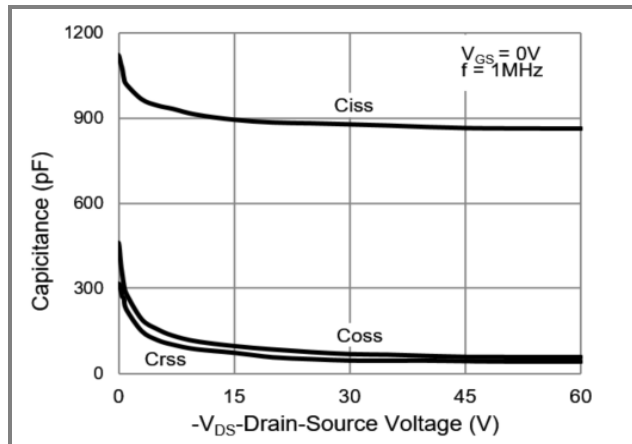


Fig.10 Capacitance vs. Drain-Source Voltage

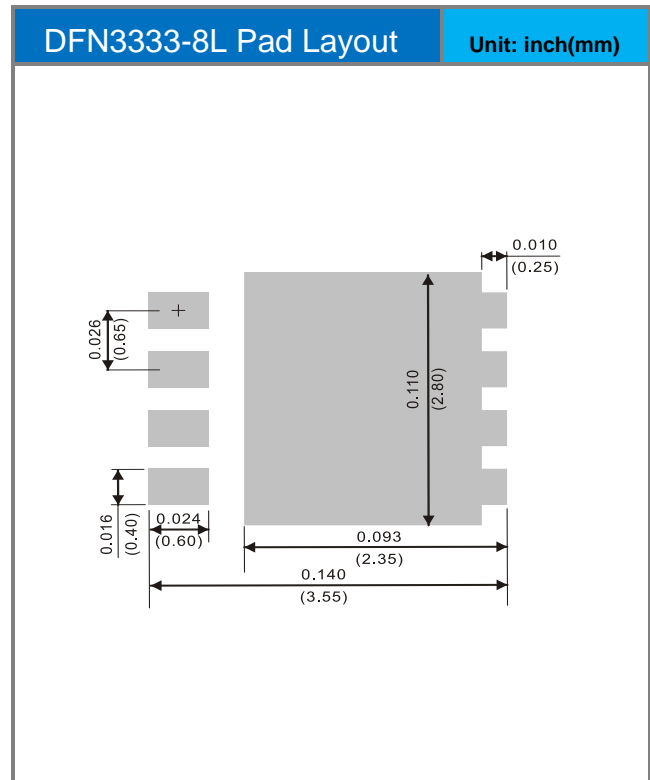
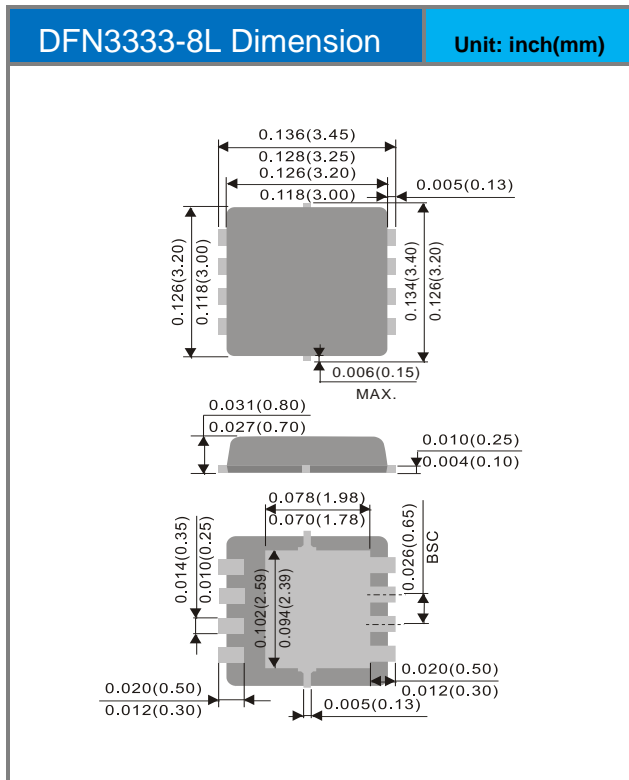


# PJQ4463AP-AU

## Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJQ4463AP-AU_R2_000A1	DFN3333-8L	5K pcs / 13" reel	4463	Halogen free

## Packaging Information & Mounting Pad Layout





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